



#### Description

The DGD0636M is a three-phase gate driver IC designed for highvoltage / high-speed applications, driving N-Channel MOSFETs and IGBTs in a half-bridge configuration. High-voltage processing techniques enable the DGD0636M's high side to switch to 100V in a bootstrap operation.

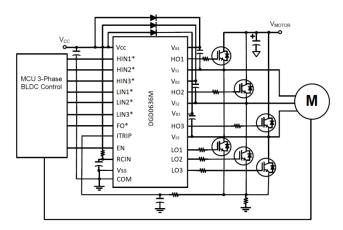
The DGD0636M logic inputs are compatible with standard TTL and CMOS levels (down to 3.3V) for easy interfacing with controlling devices and are enabled low to better function in high-noise environments. The driver outputs feature high-pulse current buffers designed for minimum driver cross conduction.

The DGD0636M offers numerous protection functions. A shootthrough protection logic prevents both outputs from being high when both inputs are high (fault state). An undervoltage lockout for VCC shuts down the respective high-side output. An overcurrent protection will terminate the six outputs. Both the VCC UVLO and the overcurrent protection trip an automatic fault clear with a timing that is adjustable with an external capacitor.

The DGD0636M is offered in SO-28 package and the operating temperature extends from -40°C to +125°C.

#### **Applications**

- 3-Phase Motor Inverter Driver
- BLDC Motor Driver
- Industrial Motor Inverter Power Tools, Robotics
- General Purpose 3-Phase Inverter



#### **Typical Configuration**

# Ordering Information (Note 4)

Product	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DGD0636MS28-13	DGD0636M	13	24	1500

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

#### DGD0636M Document Number DS41731 Rev. 1 – 2

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#### 3-PHASE HALF-BRIDGE GATE DRIVER IN SO28

#### Features

- Three Floating High-Side Drivers in Bootstrap Operation to 100V
- 200mA Source / 350mA Sink Output Current Capability
- Outputs Tolerant to Negative Transients, dV/dt Immune
- Logic Input 3.3V Capability
- Internal Deadtime of 290ns to Protect MOSFETs and IGBTs
- Matched Prop Delay for All Channels
- Outputs Out of Phase with Inputs
- Schmitt Triggered Logic Inputs
- Cross Conduction Prevention Logic
- Undervoltage Lockout for All Channels
- Overcurrent Protection Shuts Down Drivers
- Extended Temperature Range: -40°C to +125°C
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony free. "Green" Device (Note 3)

#### **Mechanical Data**

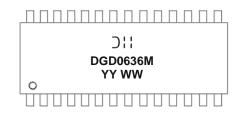
- Case: SO-28 (Type TH)
- Case Material: Molded Plastic. "Green" Molding Compound.
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminals: Finish—Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 <sup>(2)</sup>
- Weight: 0.250 grams (Approximate)



SO-28 Top View

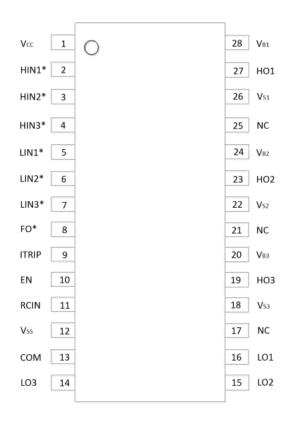


#### **Marking Information**



)'! = Manufacturer's marking DGD0636M = Product Type Marking Code YY = Year (ex: 19 = 2019) WW = Week (01 - 53)

#### **Pin Diagrams**



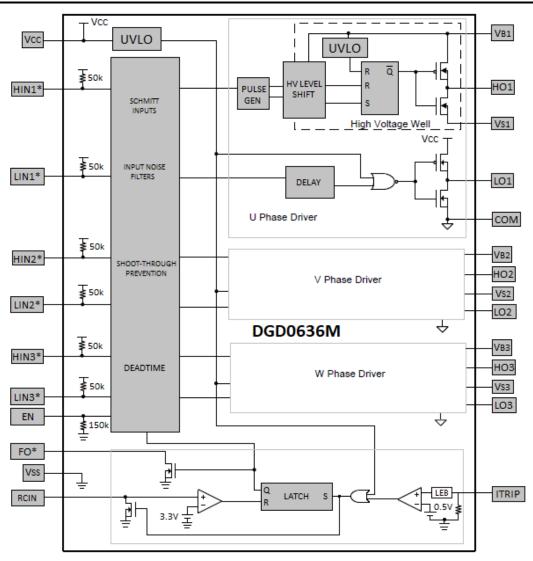
SO-28



#### **Pin Descriptions**

Pin Number	Pin Name	Function	
1	V <sub>CC</sub>	Low-Side and Logic Fixed Supply	
2,3,4	HIN1*,HIN2*,HIN3*	ogic Input for High-Side Gate Driver Output, Out of Phase with HO	
5,6,7	LIN1*,LIN2*,LIN3*	Logic Input for Low-Side Gate Driver Output, Out of Phase with LO	
8	FO*	Fault Output with Open Drain (Fault with Overcurrent and V <sub>CC</sub> UVLO)	
9	ITRIP	Analog Input for Overcurrent Shutdown	
10	EN	Logic Input for Functionality, I/O Logic Functions when EN is High	
11	RCIN	n External RC Network Input used to Define FAULT CLEAR Delay	
12	V <sub>SS</sub>	.ogic Ground	
13	COM	ow-Side Driver Return	
14,15,16	LO3,LO2,LO1	Low-Side Gate Driver Output	
17,21,25	NC	No Connection (No Internal Connection)	
18,22,26	V <sub>S3</sub> , V <sub>S2</sub> , V <sub>S1</sub>	High-Side Floating Supply Return	
19,23,27	HO3,HO2,HO1	High-Side Gate Driver Output	
20,24,28	V <sub>B3</sub> , V <sub>B2</sub> , V <sub>B1</sub>	High-Side Floating Supply	

### Functional Block Diagram





#### Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
High-Side Floating Supply Voltage	VB	-0.3 to +124	V
High-Side Floating Supply Offset Voltage	Vs	V <sub>B</sub> -24 to V <sub>B</sub> +0.3	V
High-Side Floating Output Voltage	V <sub>HO</sub>	V <sub>S</sub> -0.3 to V <sub>B</sub> +0.3	V
Low-Side Output Voltage	V <sub>LO</sub>	-0.3 to V <sub>CC</sub> +0.3	V
Offset Supply Voltage Transient	dV <sub>S</sub> /dt	50	V/ns
Low-Side Fixed Supply Voltage	V <sub>CC</sub>	-0.3 to +24	V
Logic Input Voltage (HIN*, LIN*, ITRIP, EN and FO*)	V <sub>IN</sub>	-0.3 to +5.5	V

### Thermal Characteristics ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation Linear derating factor (Note 5)	PD	2.3	W
Thermal Resistance, Junction to Ambient (Note 5)	Reja	60	°C/W
Thermal Resistance, Junction to Case (Note 5)	Rejc	45	°C/W
Operating Temperature	TJ	+150	
Lead Temperature (soldering, 10s)	TL	+300	°C
Storage Temperature Range	T <sub>STG</sub>	-55 to +150	

Note: 5. When mounted on a standard JEDEC 2-layer FR-4 board.

### **Recommended Operating Conditions**

Parameter	Symbol	Min	Max	Unit
High-Side Floating Supply Absolute Voltage	VB	V <sub>S</sub> + 10	Vs + 20	V
High-Side Floating Supply Offset Voltage	Vs	(Note 6)	100	V
High-Side Floating Output Voltage	V <sub>HO</sub>	Vs	VB	V
Low-Side Fixed Supply Voltage	Vcc	10	20	V
Low-Side Output Voltage	V <sub>LO</sub>	COM	V <sub>CC</sub>	V
Logic Input Voltage (HIN*, LIN*, ITRIP & EN)	V <sub>IN</sub>	V <sub>SS</sub>	5	V
Fault Output Voltage	V <sub>FO</sub>	V <sub>SS</sub>	V <sub>CC</sub>	V
Logic Ground	V <sub>SS</sub>	-5	5	V
Ambient Temperature	T <sub>A</sub>	-40	+125	C°

Note: 6. Logic operation for  $V_S$  of -5V to +100V.



## DC Electrical Characteristics (V<sub>BIAS</sub> (V<sub>CC</sub>, V<sub>BS</sub>) = 15V, @T<sub>A</sub> = +25°C, unless otherwise specified.) (Note 7)

Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Logic "0" Input Voltage	VIH	2.4	тур		V	
Logic "1" Input Voltage	VIH	<u> </u>		0.8	V	
High Level Output Voltage, V <sub>BIAS</sub> - V <sub>O</sub>	V <sub>OH</sub>		<u> </u>	0.0	V	$I_{O} = 0 m A$
Low Level Output Voltage, VBIAS VO	VOH VOL		_	0.1	V	$I_0 = 0$ mA
Offset Supply Leakage Current				10	μA	$V_B = V_S = 100V$
Quiescent V <sub>BS</sub> Supply Current	I <sub>LK</sub> I <sub>BSQ</sub>	10	85	130	μA	$V_{\rm IN} = 0V \text{ or } 5V, \text{EN} = 0V$
Quiescent V <sub>CC</sub> Supply Current	lccq		1.1	1.6	mA	$V_{IN} = 0V \text{ or } 5V, EN = 0V$
Logic Input Bias Current (HO=LO=HIGH)	IIN+		130	200	μA	$V_{\rm IN} = 0V$
Logic Input Bias Current (HO=LO=LOW)	I <sub>IN-</sub>		3.0	20	μΑ	$V_{IN} = 5V$
Logic Enable "1" Input Bias Current	I <sub>EN+</sub>	_	33	80	μA	$V_{EN} = 5V$
Logic Enable "0" Input Bias Current	I <sub>EN-</sub>	—	_	2.0	μA	$V_{EN} = 0V$
V <sub>BS</sub> Supply Undervoltage Positive Going Threshold	V <sub>BSUV+</sub>	7.6	8.9	9.9	V	—
V <sub>BS</sub> Supply Undervoltage Negative Going Threshold	V <sub>BSUV-</sub>	7.1	8.3	9.4	V	—
V <sub>CC</sub> Supply Undervoltage Positive Going Threshold	V <sub>CCUV+</sub>	7.6	8.9	9.9	V	—
V <sub>CC</sub> Supply Undervoltage Negative Going Threshold	V <sub>CCUV-</sub>	7.1	8.3	9.4	V	—
Output High Short Circuit Pulsed Current	I <sub>O+</sub>	120	200	—	mA	V <sub>O</sub> = 0V, PW ≤ 10µs
Output Low Short Circuit Pulsed Current	lo-	250	350	—	mA	V <sub>O</sub> = 15V, PW ≤ 10µs
Overcurrent Detect Positive Threshold	VITH+	400	500	600	mV	—
Overcurrent Detect Negative Threshold	VITH-	340	420	500	mV	—
Short-Circuit Input Current	ICSIN	6.0	11	16	μA	V <sub>CSIN</sub> = 1V
RCIN Positive Going Threshold Voltage	V <sub>RCINTH+</sub>	7.0	8.4	9.8	V	—
RCIN Negative Going Threshold Voltage	V <sub>RCINTH-</sub>	—	5.0	—	V	—
Fault Output Low Level Voltage	V <sub>FOL</sub>	—	0.2	0.5	V	$V_{CS} = 1V, I_{FO} = 1.5mA$
RCIN on Resistance	R <sub>DSRCIN</sub>	40	75	110	Ω	$I_{RCIN} = 1.5 mA$
Fault Output on Resistance	RDSFO	80	130	180	Ω	I <sub>FO</sub> = 1.5mA

Note: 7. The V<sub>IN</sub>, V<sub>TH</sub>, and I<sub>IN</sub> parameters are referenced to V<sub>SS</sub> and are applicable to all six channels (HIN1\*,2\*,3\* and LIN1\*,2\*,3\*). The V<sub>O</sub> and I<sub>O</sub> parameters are applicable to the output pins (HO1,2,3 and LO1,2,3) and are referenced to COM.

## AC Electrical Characteristics (V<sub>BIAS</sub> (V<sub>CC</sub>, V<sub>BS</sub>) = 15V, C<sub>L</sub> = 1000pF, @T<sub>A</sub> = +25°C, unless otherwise specified.)

Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Turn-On Propagation Delay	t <sub>ON</sub>	200	330	460	ns	$V_{\rm S} = 0V$
Turn-Off Propagation Delay	tOFF	200	330	460	ns	$V_{\rm S} = 0V$
Turn-On Rise Time	tr	—	90	150	ns	$V_{\rm S} = 0V$
Turn-Off Fall Time	t <sub>f</sub>	—	35	60	ns	$V_{\rm S} = 0V$
Delay Matching	t <sub>DM</sub>	—	_	50	ns	—
Enable Low to Output Shutdown Delay	t <sub>EN</sub>	225	330	425	ns	—
ITRIP Pin Leading-Edge Blanking Time	t <sub>BLT</sub>	200	300	400	ns	—
Time from ITRIP Triggering to FO*	tFLT	360	550	760	ns	From V <sub>ITRIP</sub> = 1V to FO* turn off
Time from ITRIP Triggering to All Gate Outputs Turn Off	tITRIP	420	615	820	ns	From V <sub>ITRIP</sub> = 1V to starting gate turn off
Input Filtering Time (HIN*, LIN*, EN)	<b>t</b> FLTIN	—	250	—	ns	—
Fault Clear Time	<b>t</b> FLTCLR	—	1.6	—	ms	C <sub>RCIN</sub> = 1nF, R <sub>RCIN</sub> = 2Mw
Deadtime	t <sub>DT</sub>	200	290	420	ns	—
Deadtime Matching	t <sub>DTM</sub>	—	_	50	ns	—
Output Pulse Width Matching (Note 8)	t <sub>PM</sub>		50	75	ns	PW <sub>IN</sub> > 1µs

Note: 8.  $t_{PM}$  is defined as  $PW_{IN}$  -  $PW_{OUT}$ .



### **Timing Waveforms**

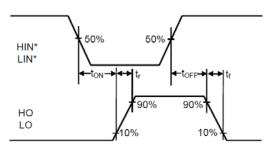
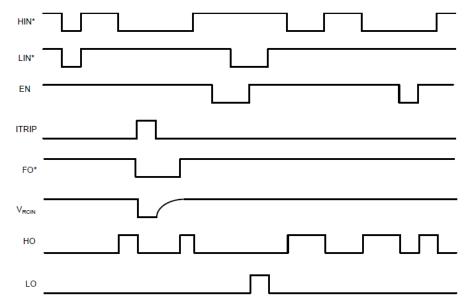
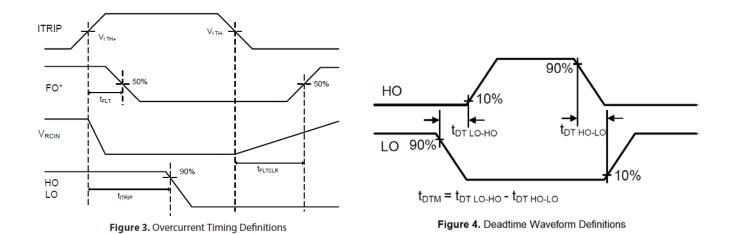


Figure 1. Switching Time Waveform Definitions









### Typical Performance Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

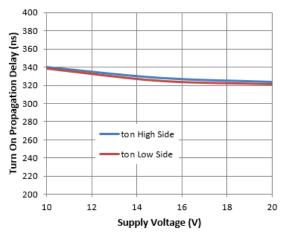


Figure 5. Turn-on Propagation Delay vs. Supply Voltage

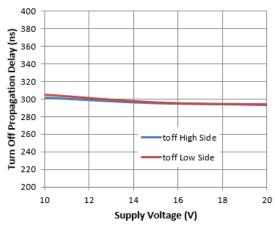


Figure 7. Turn-off Propagation Delay vs. Supply Voltage

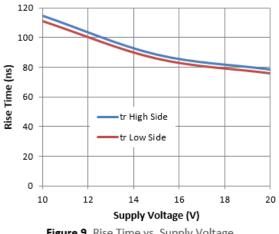


Figure 9. Rise Time vs. Supply Voltage

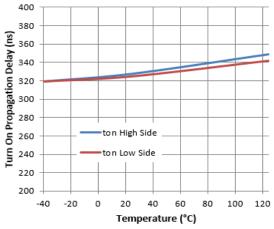


Figure 6. Turn-on Propagation Delay vs. Temperature

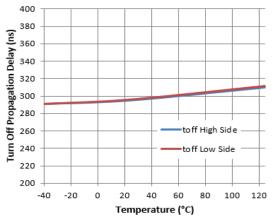


Figure 8. Turn-off Propagation Delay vs. Temperature

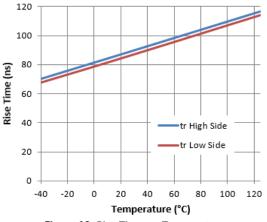


Figure 10. Rise Time vs. Temperature



### Typical Performance Characteristics (continued)

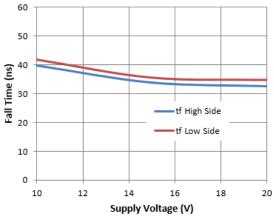


Figure 11. Fall Time vs. Supply Voltage

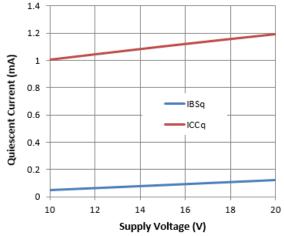
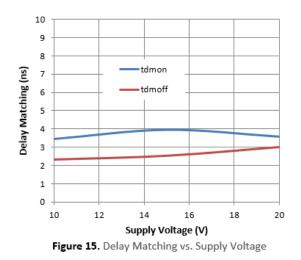


Figure 13. Quiescent Current vs. Supply Voltage



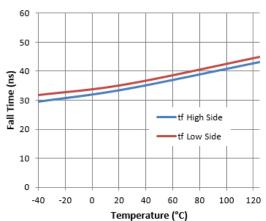
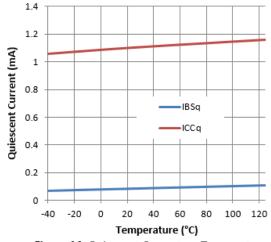


Figure 12. Fall Time vs. Temperature





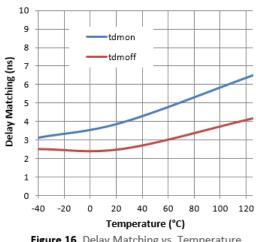


Figure 16. Delay Matching vs. Temperature



### Typical Performance Characteristics (cont.)

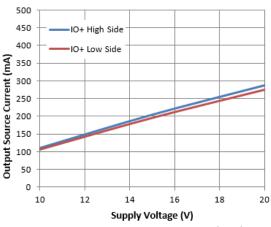


Figure 17. Output Source Current vs. Supply Voltage

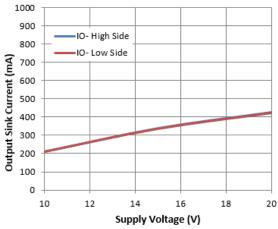


Figure 19. Output Sink Current vs. Supply Voltage

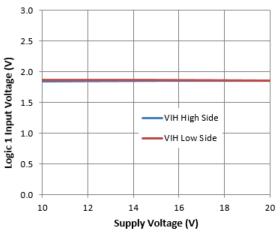


Figure 21. Logic 1 Input Voltage vs. Supply Voltage

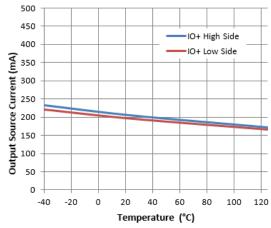
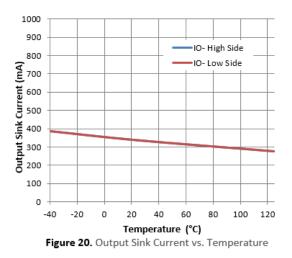
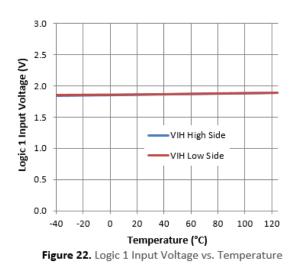


Figure 18. Output Source Current vs. Temperature







### Typical Performance Characteristics (cont.)

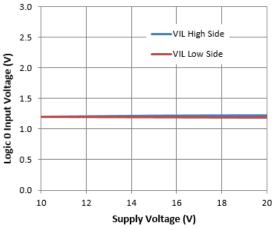
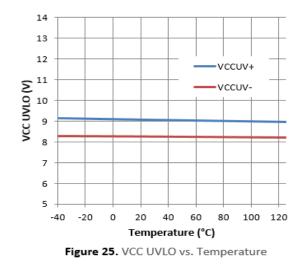


Figure 23. Logic 0 Input Voltage vs. Supply Voltage



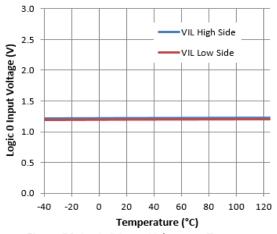


Figure 24. Logic 0 Input Voltage vs. Temperature

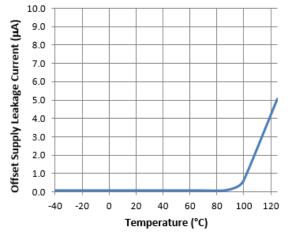


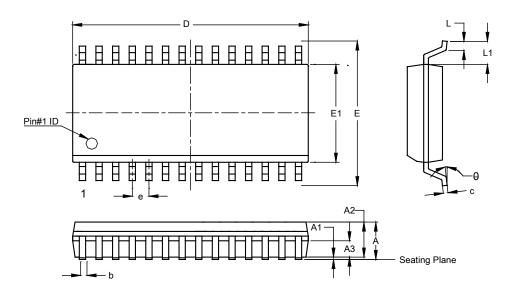
Figure 26. Offset Supply Leakage Current vs. Temperature



#### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

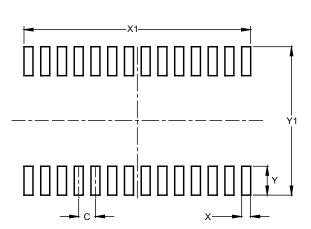




	SO-28 (Type TH)						
Dim	Min						
Α		2.65					
A1	0.10	0.30					
A2	2.25	2.35	2.30				
A3	0.97	1.07	1.02				
b	0.39	0.48					
c	0.25	0.31					
D	17.80	18.20	18.00				
Е	10.10	10.50	10.30				
E1	7.30	7.70	7.50				
e	1.27 BSC						
L	0.70	1.00					
L1		1.40 BS	С				
θ	0°	8°					
All Dimensions in mm							

### **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	1.270
Х	0.680
X1	17.190
Y	2.200
Y1	11.300

Note: For high-voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.

SO-28 (Type TH)



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